17 W Dual BTL Audio Power Amplifier

The HA13127/HA13130 are high output and low distortion dual BTL power IC designed for car stereo amplifiers.

At 14.4 V to 4 Ω load, this power IC provides an output power 17 W with 10 % distortion.

Features

- Stand-by circuit included. Can be switched on & off easily by microcomputer.
- Output capacitors not required. These IC employ internal ASO protection circuit of high reliability current shutdown type, which can protect speaker.
- Surge protection circuit and thermal shutdown circuit are included. Thermal shutdown is high speed and hysteresis on & off type.
- · Can be used without bootstrap capacitor.
- Low total harmonic distortion in wide frequency range

THD = 0.05 % Typ (f = 50 Hz) THD = 0.05 % Typ (f = 1 kHz) THD = 0.07 % Typ (f = 10 kHz) THD = 0.1 % or less (Pout = 1.5 W, f = 20 Hz to 20 kHz)

Ordering Information

Туре No.	Voltage gain	Package				
HA13127	50 dB	16 pin SIP with heat sink				
HA13130	40 dB	- With Hoat Sink				

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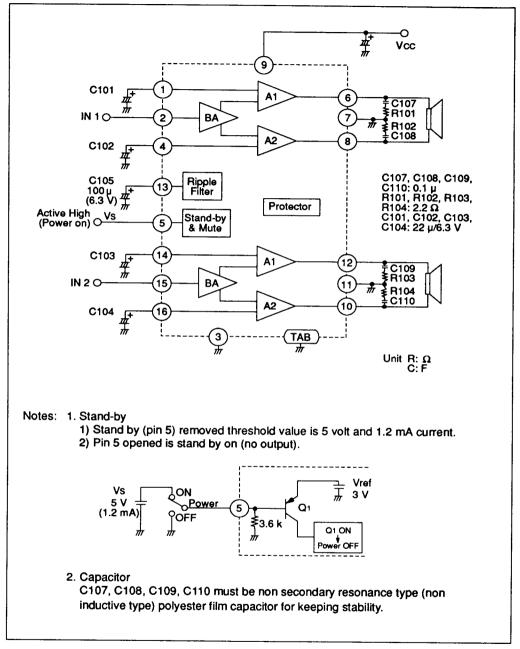


Figure 1 Block Diagram

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Absolute Maximum Ratings (Ta = 25 °C)

item	Symbol	Rating	Unit	Notes	
Operating supply voltage	Vcc	18	V		
DC supply voltage	Vcc (DC)	26	V	1	
Peak supply voltage	Vcc (Peak)	50	v	2	
Output current	lo (peak)	4	Α	Per channel	
Power dissipation	Рт	25	W	···· •·· · · · · · · · · · · · · · · ·	
Junction temperature	Tj	150	°C		
Operating temperature	Торг	30 to +85	°C		
Storage temperature	Tstg	-55 to +125	°C		

Notes: 1. Value at $t \le 30$ sec

2. Value at surge wave-form (rise time $t \ge 1$ ms)

Electrical Characteristics (Vcc = 13.2 V, f = 1 kHz, RL = 4 Ω , dual operation, Ta = 25 °C)

HA13127 (Gv = 50 dB) HA13130 (Gv = 40 dB)

Item	Symbol								
		Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Quiescent current	KQ1	60	150	250	60	150	250	mA	Vin = 0 V
Input bias voltage	VB	_	20	40	_	20	40	mV	Vin = 0 V
Output offset voltage	ΔVo	_	0	150	_	0	150	mV	Vin = 0 V
Voltage gain	Gv	48.5	50	51.5	38.5	40	41.5	dB	
Difference of voltage gain	ΔGv	-	_	1.5	_	_	1.5	dB	
Output power (1)	Poi	10	14	-	10	14	_	W	Vcc = 13.2 V THD = 10 %
Output power (2)	Poz	-	17	-	_	17		W	Vcc = 14.4 V THD = 10 %
Output power (3)	Pos	_	6	-	-	11	_	w	Vcc = 13.2 V THD = 1 %
Total harmonic distortion	THD	<u></u>	0.2	0.7	_	0.04	0.15	%	Pout = 1.5 W

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Electrical Characte	ristics (Ve	c = 13.2	2 V, f =	1 kHz, 1	$\mathbf{R}\mathbf{L}=4$	I Ω, dua	l opera	tion, I	a = 25 °C) (cont)
Noise output (1)	WBN1	_	1.0	2.0	-	0.35	0.7	mV	$Rg = 10 k\Omega$ BW = 20 Hz to 20 kHz
Noise output (2)	WBN2	_	0.8	1.7	-	0.25	0.5	mV	Rg = 0 BW = 20 Hz to 20 kHz
Supply voltage rejection ratio	SVR	32	40		45	60		dB	f = 500 Hz, Vripple = 0 dBm
Low roll-off Frequency	fια		20			10		Hz	$\Delta Gv = -3 dB$ from
High roll-off frequency	fR α.	_	20		30	70	140	kHz	f = 1 kHz
Stand-by current	ka2	_	50	200	_	50	200	μΑ	V 5 Open
Stand-by	VTH (H)	5	_	Vcc-1	5	_	Vcc-1	٧	Vin=50 dBm Output or
threshold voltage	VTH (L)	0	_	1	0	_	1	٧	Output off
Stand-by (Mute) signal reduction level	ATT	45	60	_	45	60	_	dB	Vin = -50 dBm
Stand-by (Mute) on time	tr		10	_	_	10	_	μs	V1 = 3 V to Open (Power on to off)
Stand-by (Mute) off time	tra		0.2	_	_	0.2	_	sec	V1 = Open to 3 V (Power off to on)
Input impedance	Rin	20	30	40	20	30	40	kΩ	
Channel cross-talk	СТ	_	60	_	45	60		dB	Vout = 0 dBm
Output power (4)	Po4	_	10	_	_	10	_	W	THD = 10 % RL = 8 Ω
Output power (5)	Pos		7			7	_	W	THD = 1 % RL = 8 Ω

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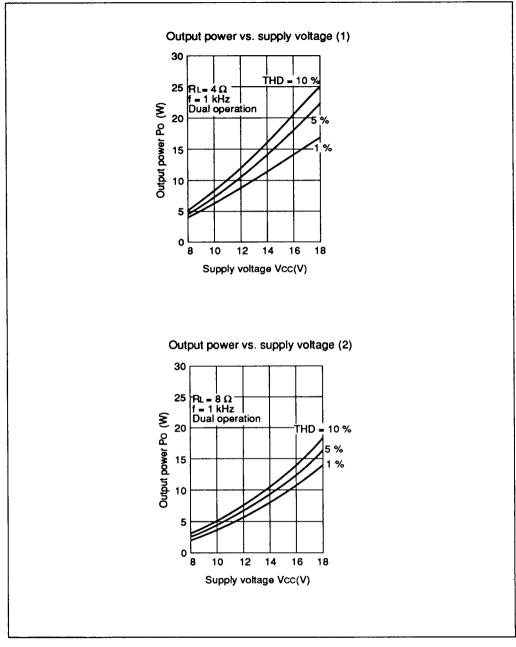


Figure 2 HA13130 Characteristic Curves

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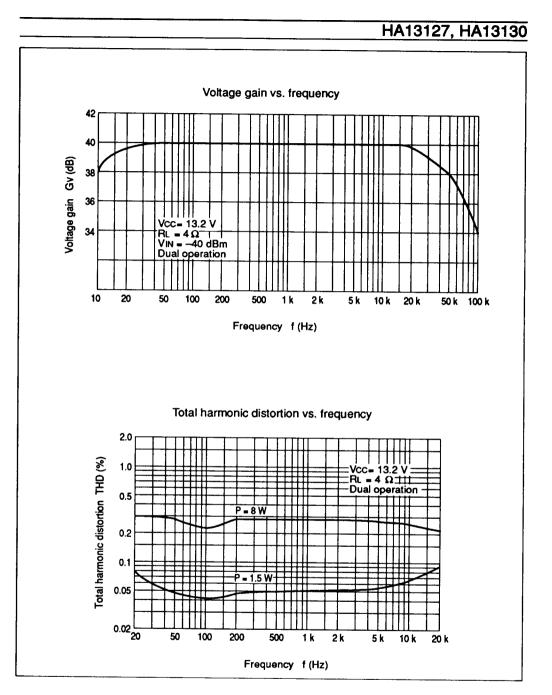


Figure 2 HA13130 Characteristic Curves (cont)

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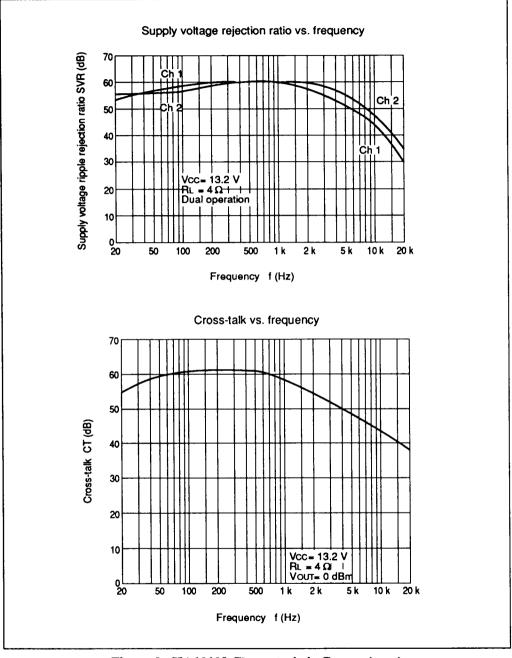


Figure 2 HA13130 Characteristic Curves (cont)

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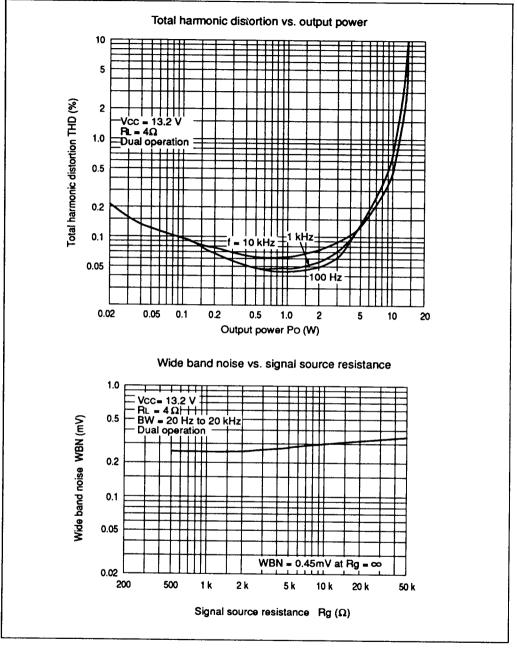


Figure 2 HA13130 Characteristic Curves (cont)

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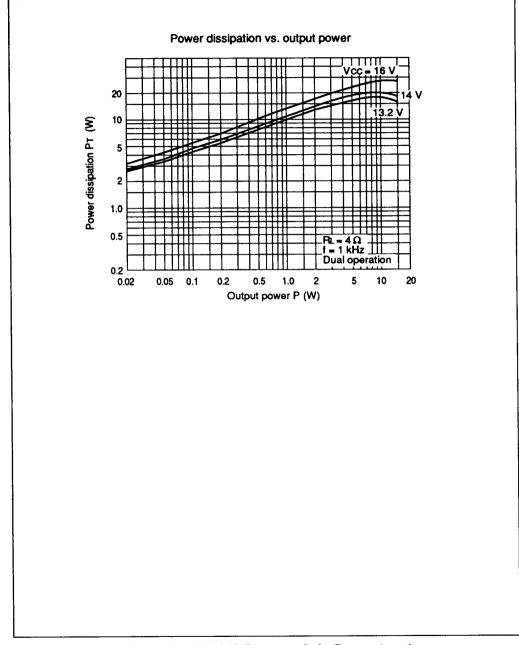


Figure 2 HA13130 Characteristic Curves (cont)

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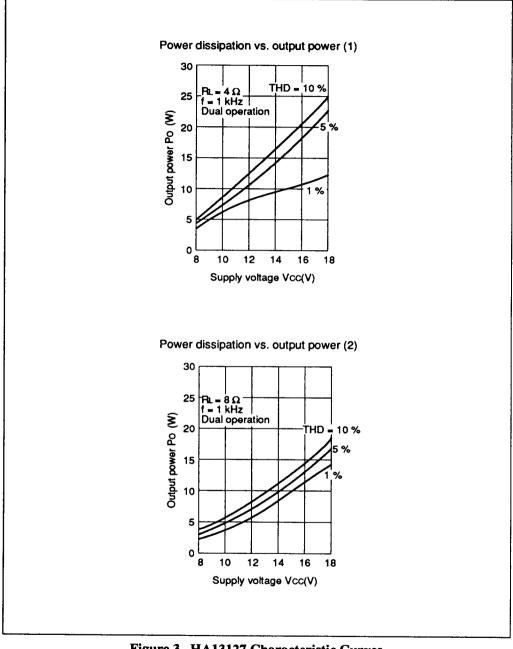


Figure 3 HA13127 Characteristic Curves

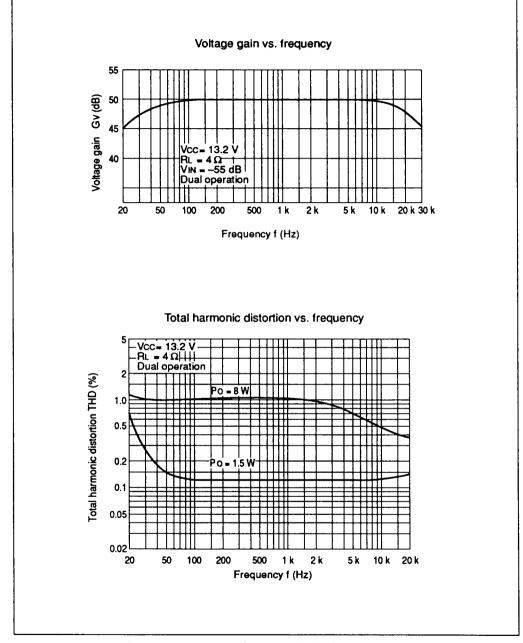


Figure 3 HA13127 Characteristic Curves (cont)

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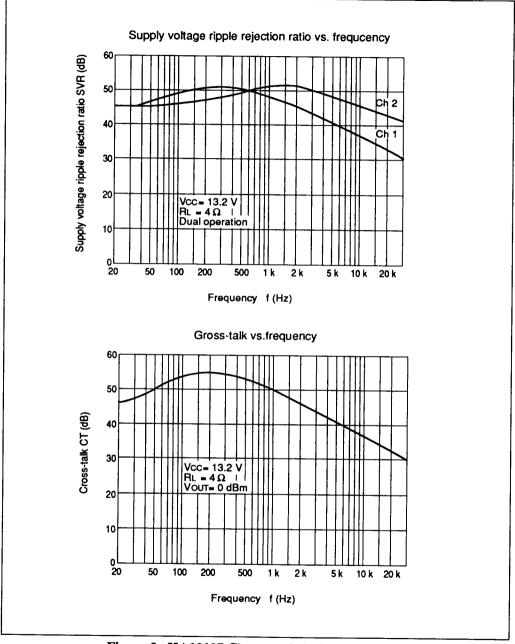


Figure 3 HA13127 Characteristic Curves (cont)

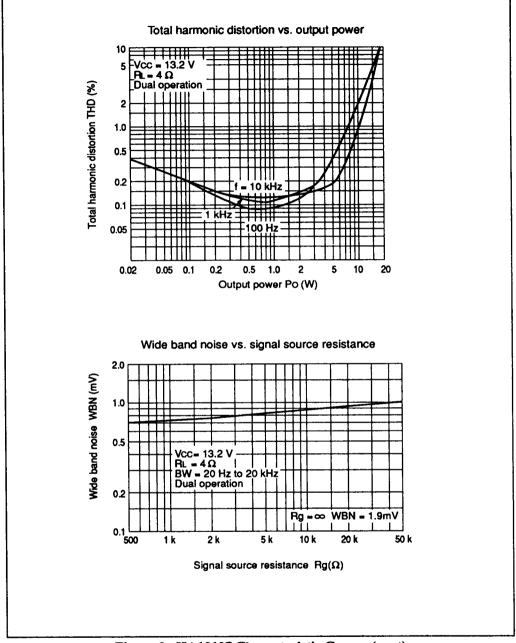


Figure 3 HA13127 Characteristic Curves (cont)

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